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LM4818 Boomer® Audio Power Amplifier Series 350mW Audio Power Amplifier with Shutdown Mode

Check for Samples: [LM4818](#)

FEATURES

- SOIC Surface Mount Packaging.
- Switch On/Off Click Suppression.
- Unity-Gain Stable.
- Minimum External Components.

APPLICATIONS

- General Purpose Audio
- Portable Electronic Devices
- Information Appliances (IA)

KEY SPECIFICATIONS

- THD+N at 1kHz, 350mW Continuous Average Output Power into 16Ω 10% (max)
- THD+N at 1kHz, 300mW Continuous Average Output Power into 8Ω 10% (max)
- Shutdown Current 0.7µA (typ)

Typical Application

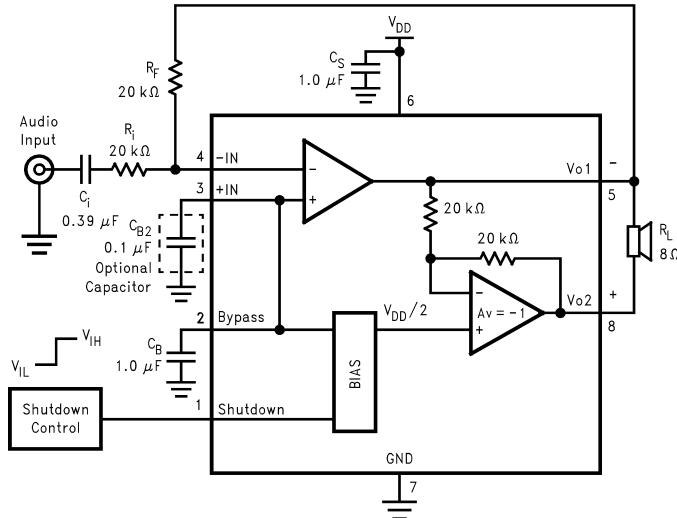


Figure 1. Typical Audio Amplifier Application Circuit

DESCRIPTION

The LM4818 is a mono bridged power amplifier that is capable of delivering 350mW_{RMS} output power into a 16Ω load or 300mW_{RMS} output power into an 8Ω load with 10% THD+N from a 5V power supply.

The LM4818 Boomer™ audio power amplifier is designed specifically to provide high quality output power and minimize PCB area with surface mount packaging and a minimal amount of external components. Since the LM4818 does not require output coupling capacitors, bootstrap capacitors or snubber networks, it is optimally suited for low-power portable applications.

The closed loop response of the unity-gain stable LM4818 can be configured using external gain-setting resistors. The device is available in SOIC package type to suit various applications.

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Connection Diagram

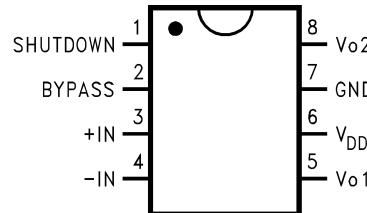


Figure 2. SOIC Package - Top View
See Package Number D



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾⁽²⁾⁽³⁾

| | | | |
|--|--------------------------------|--------------------------|---------|
| Supply Voltage | 6.0V | | |
| Storage Temperature | -65°C to +150°C | | |
| Input Voltage | -0.3V to V _{DD} +0.3V | | |
| Power Dissipation (P _D) ⁽⁴⁾ | Internally Limited | | |
| ESD Susceptibility ⁽⁵⁾ | 2.5kV | | |
| ESD Susceptibility ⁽⁶⁾ | 200V | | |
| Junction Temperature (T _J) | 150°C | | |
| Soldering Information | Small Outline Package | Vapor Phase (60 seconds) | 215°C |
| | | Infrared (15 seconds) | 220°C |
| Thermal Resistance | | θ _{JC} (SOIC) | 35°C/W |
| | | θ _{JA} (SOIC) | 170°C/W |

- (1) All voltages are measured with respect to the ground pin, unless otherwise specified.
- (2) *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur. *Operating Ratings* indicate conditions for which the device is functional, but do not ensure specific performance limits. *Electrical Characteristics* state DC and AC electrical specifications under particular test conditions which ensure specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not ensured for parameters where no limit is given. However, the typical value is a good indication of device's performance.
- (3) If Military/Aerospace specified devices are required, please contact the Texas Instruments Sales Office/Distributors for availability and specifications.
- (4) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA}, and the ambient temperature T_A. The maximum allowable power dissipation is P_{DMAX} = (T_{JMAX} - T_A)/θ_{JA}. For the LM4818, T_{JMAX} = 150°C and the typical junction-to-ambient thermal resistance (θ_{JA}) when board mounted is 170°C/W for the SOIC package.
- (5) Human body model, 100pF discharged through a 1.5 kΩ resistor.
- (6) Machine Model, 220pF–240pF capacitor is discharged through all pins.

OPERATING RATINGS⁽¹⁾⁽²⁾

| | |
|--|-------------------------------|
| Temperature Range T _{MIN} ≤ T _A ≤ T _{MAX} | -40°C ≤ T _A ≤ 85°C |
| Supply Voltage | 2.0V ≤ V _{CC} ≤ 5.5V |

- (1) All voltages are measured with respect to the ground pin, unless otherwise specified.
- (2) *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur. *Operating Ratings* indicate conditions for which the device is functional, but do not ensure specific performance limits. *Electrical Characteristics* state DC and AC electrical specifications under particular test conditions which ensure specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not ensured for parameters where no limit is given. However, the typical value is a good indication of device's performance.

ELECTRICAL CHARACTERISTICS $V_{DD} = 5V^{(1)(2)}$

The following specifications apply for $V_{DD} = 5V$, $R_L = 16\Omega$ unless otherwise stated. Limits apply for $T_A = 25^\circ C$.

| Symbol | Parameter | Conditions | LM4818 | | Units (Limits) |
|------------|-----------------------------------|--|------------------------|-------------------------|----------------|
| | | | Typical ⁽³⁾ | Limit ⁽⁴⁾⁽⁵⁾ | |
| I_{DD} | Quiescent Power Supply Current | $V_{IN} = 0V$, $I_o = 0A$ | 1.5 | 3.0 | mA (max) |
| I_{SD} | Shutdown Current | $V_{PIN1} = V_{DD}^{(6)}$ | 1.0 | 5.0 | μA (max) |
| I_{SDIH} | Shutdown Voltage Input High | | | 4.0 | V (min) |
| I_{SDIL} | Shutdown Voltage Input Low | | | 1.0 | V (max) |
| V_{OS} | Output Offset Voltage | $V_{IN} = 0V$ | 5 | 50 | mV (max) |
| P_o | Output Power | THD = 10%, $f_{IN} = 1kHz$ | 350 | | mW |
| | | THD = 10%, $f_{IN} = 1kHz$, $R_L = 8\Omega$ | 300 | | mW |
| THD+N | Total Harmonic Distortion + Noise | $P_o = 270mW_{RMS}$, $A_{VD} = 2$, $f_{IN} = 1kHz$ | 1 | | % |

(1) All voltages are measured with respect to the ground pin, unless otherwise specified.

(2) *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur. *Operating Ratings* indicate conditions for which the device is functional, but do not ensure specific performance limits. *Electrical Characteristics* state DC and AC electrical specifications under particular test conditions which ensure specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not ensured for parameters where no limit is given. However, the typical value is a good indication of device's performance.

(3) Typical specifications are specified at $25^\circ C$ and represent the parametric norm.

(4) Tested limits are specified to TI's AOQL (Average Outgoing Quality Level).

(5) Datasheet min/max specification limits are specified by designs, test, or statistical analysis.

(6) The Shutdown pin (pin 1) should be driven as close as possible to V_{DD} for minimum current in Shutdown Mode.

ELECTRICAL CHARACTERISTICS $V_{DD} = 3V^{(1)(2)}$

The following specifications apply for $V_{DD} = 3V$ and $R_L = 16\Omega$ load unless otherwise stated. Limits apply to $T_A = 25^\circ C$.

| Symbol | Parameter | Conditions | LM4818 | | Units (Limits) |
|------------|-----------------------------------|---|------------------------|-------------------------|----------------|
| | | | Typical ⁽³⁾ | Limit ⁽⁴⁾⁽⁵⁾ | |
| I_{DD} | Quiescent Power Supply Current | $V_{IN} = 0V$, $I_o = 0A$ | 1.0 | 3.0 | mA (max) |
| I_{SD} | Shutdown Current | $V_{PIN1} = V_{DD}^{(6)}$ | 0.7 | 5.0 | μA (max) |
| I_{SDIH} | Shutdown Voltage Input High | | | 2.4 | V (min) |
| I_{SDIL} | Shutdown Voltage Input Low | | | 0.6 | V (max) |
| V_{OS} | Output Offset Voltage | $V_{IN} = 0V$ | 5 | 50 | mV |
| P_o | Output Power | THD = 10%, $f_{IN} = 1kHz$ | 110 | | mW |
| | | THD = 10%, $f_{IN} = 1kHz$, $R_L = 8\Omega$ | 90 | | mW |
| THD+N | Total Harmonic Distortion + Noise | $P_o = 80mW_{RMS}$, $A_{VD} = 2$, $f_{IN} = 1kHz$ | 1 | | % |

(1) All voltages are measured with respect to the ground pin, unless otherwise specified.

(2) *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur. *Operating Ratings* indicate conditions for which the device is functional, but do not ensure specific performance limits. *Electrical Characteristics* state DC and AC electrical specifications under particular test conditions which ensure specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not ensured for parameters where no limit is given. However, the typical value is a good indication of device's performance.

(3) Typical specifications are specified at $25^\circ C$ and represent the parametric norm.

(4) Tested limits are specified to TI's AOQL (Average Outgoing Quality Level).

(5) Datasheet min/max specification limits are specified by designs, test, or statistical analysis.

(6) The Shutdown pin (pin 1) should be driven as close as possible to V_{DD} for minimum current in Shutdown Mode.

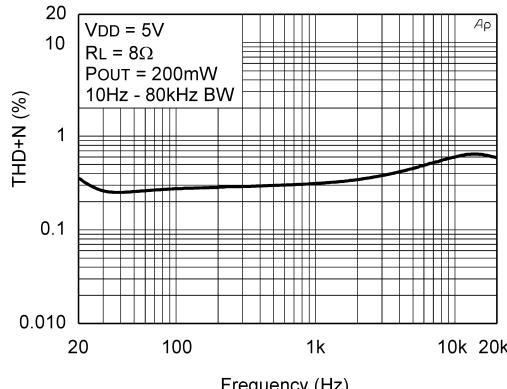
EXTERNAL COMPONENTS DESCRIPTION

(Figure 1)

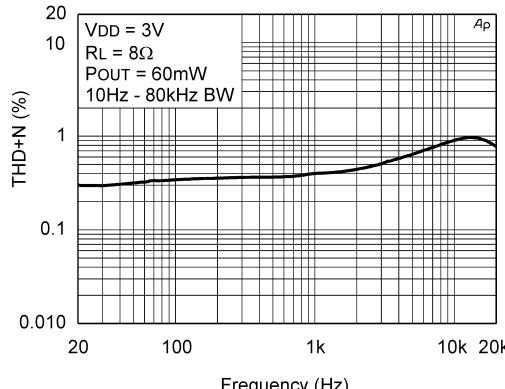
| Components | Functional Description |
|-------------|--|
| 1. R_i | Combined with R_f , this inverting input resistor sets the closed-loop gain. R_i also forms a high pass filter with C_i at $f_c = 1/(2\pi R_i C_i)$. |
| 2. C_i | This input coupling capacitor blocks DC voltage at the amplifier's terminals. Combined with R_i , it creates a high pass filter with R_i at $f_c = 1/(2\pi R_i C_i)$. Refer to the section, PROPER SELECTION OF EXTERNAL COMPONENTS for an explanation of how to determine the value of C_i . |
| 3. R_f | Combined with R_i , this is the feedback resistor that sets the closed-loop gain: $A_v = 2(R_f/R_i)$. |
| 4. C_s | This is the power supply bypass capacitor that filters the voltage applied to the power supply pin. Refer to the APPLICATION INFORMATION section for proper placement and selection of C_s . |
| 5. C_B | This is the bypass pin capacitor that filters the voltage at the BYPASS pin. Refer to the section, PROPER SELECTION OF EXTERNAL COMPONENTS for information concerning proper placement and selection of C_B . |
| 6. C_{B2} | This is an optional capacitor that is not needed in the majority of applications. If the capacitor is not used, pin 3 should be connected directly to pin2. Refer to the section PROPER SELECTION OF EXTERNAL COMPONENTS for more information concerning C_{B2} . |

TYPICAL PERFORMANCE CHARACTERISTICS

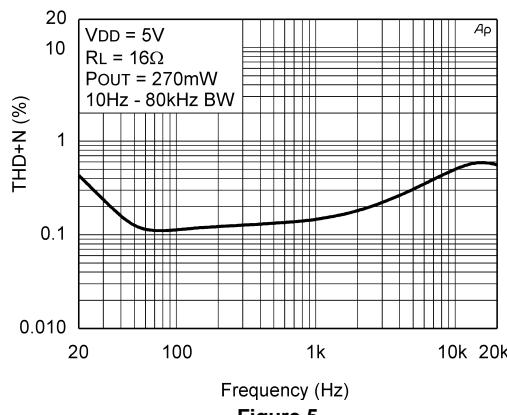
THD+N vs Frequency



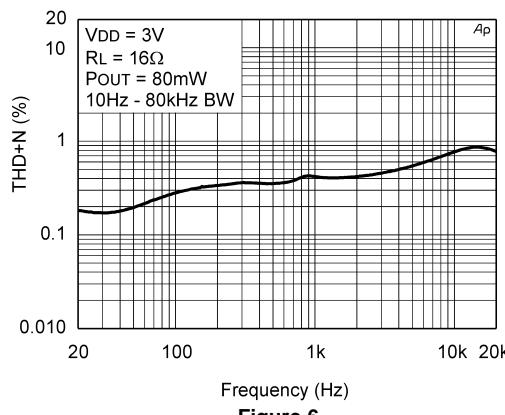
THD+N vs Frequency



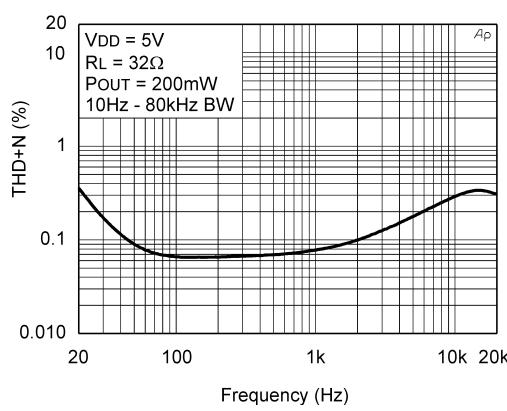
THD+N vs Frequency



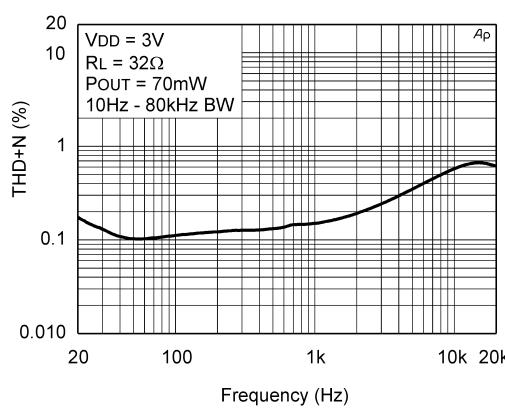
THD+N vs Frequency



THD+N vs Frequency



THD+N vs Frequency



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

THD+N vs Output Power

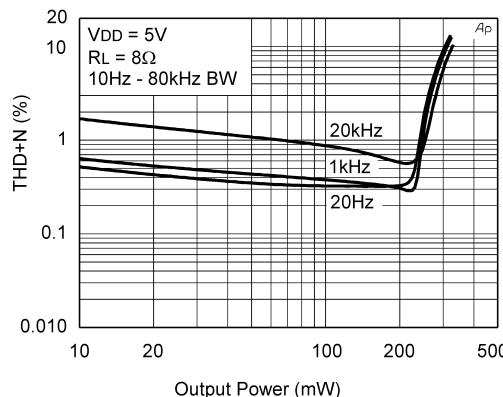


Figure 9.

THD+N vs Output Power

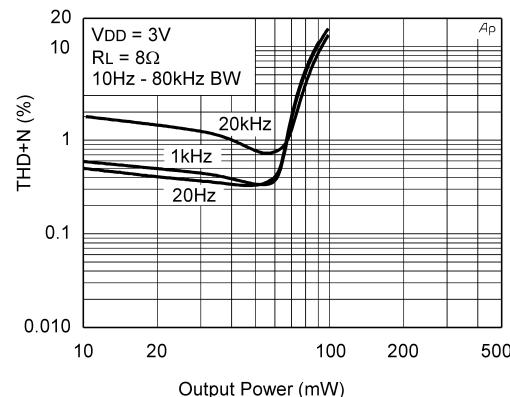


Figure 10.

THD+N vs Output Power

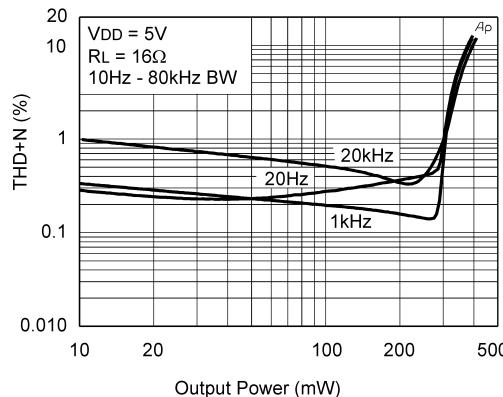


Figure 11.

THD+N vs Output Power

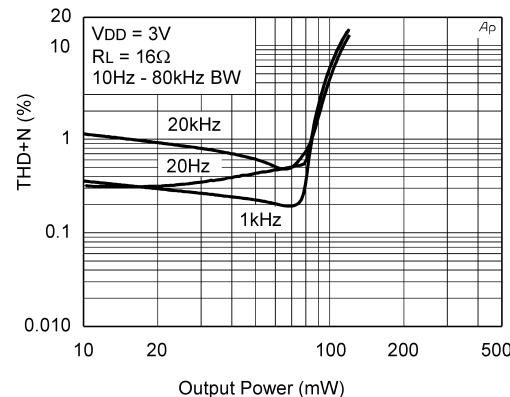


Figure 12.

THD+N vs Output Power

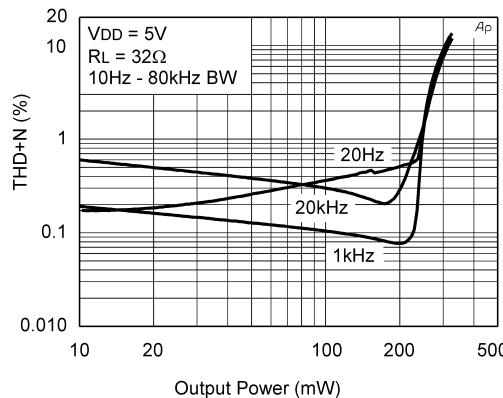


Figure 13.

THD+N vs Output Power

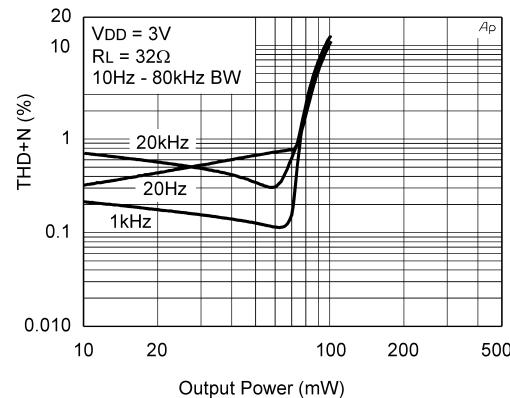


Figure 14.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Output Power vs Supply Voltage

$R_L = 8\Omega$

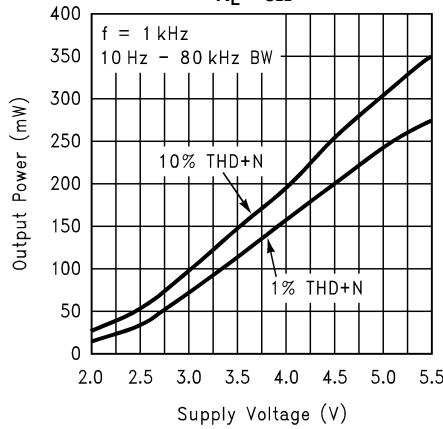


Figure 15.

Output Power vs Supply Voltage

$R_L = 16\Omega$

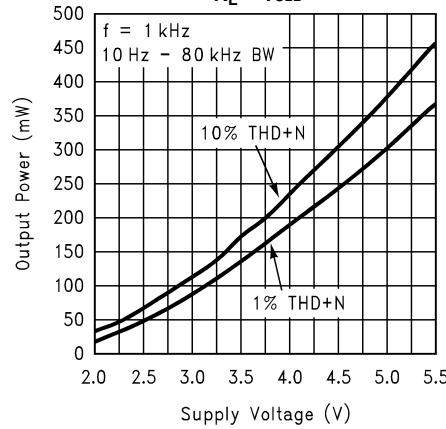


Figure 16.

Output Power vs Supply Voltage

$R_L = 32\Omega$

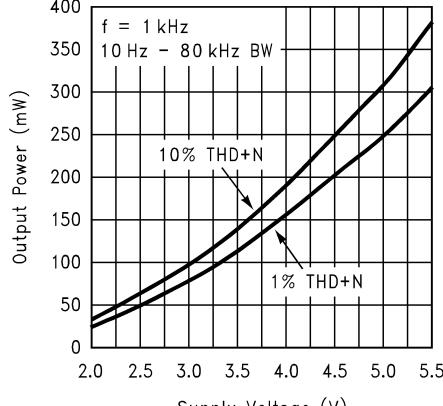


Figure 17.

Output Power vs Load Resistance

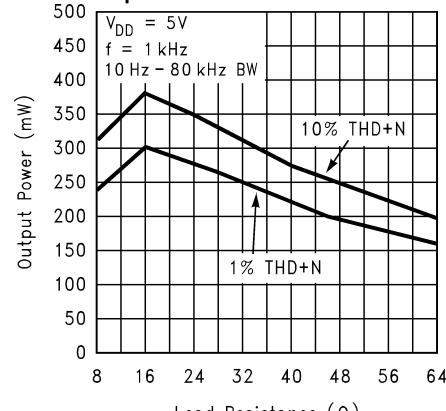


Figure 18.

**Power Dissipation vs
Output Power**

$V_{DD} = 5V$

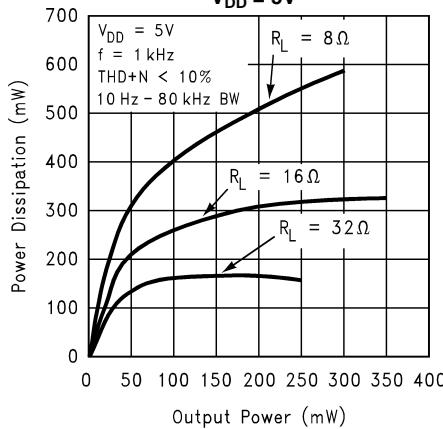


Figure 19.

**Power Dissipation vs
Output Power**

$V_{DD} = 3V$

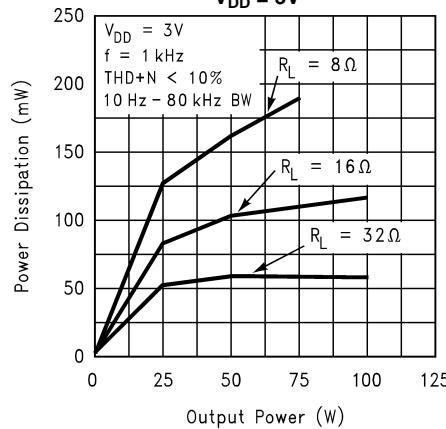


Figure 20.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

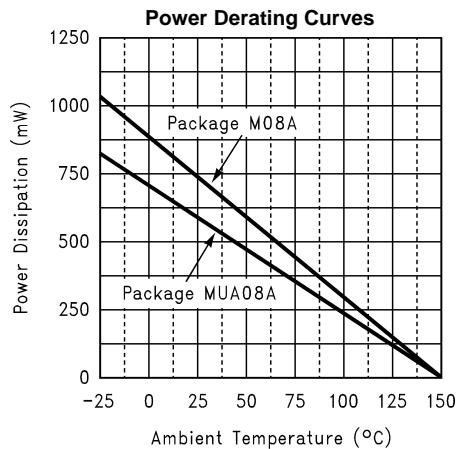


Figure 21.

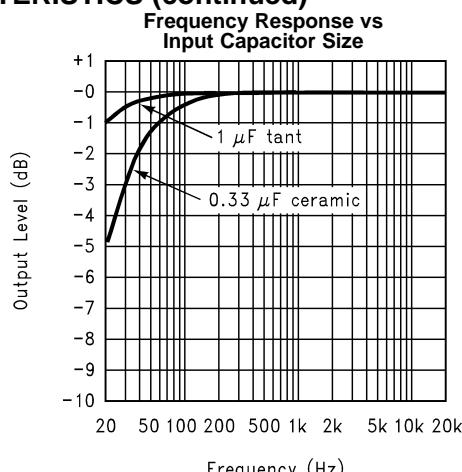


Figure 22.

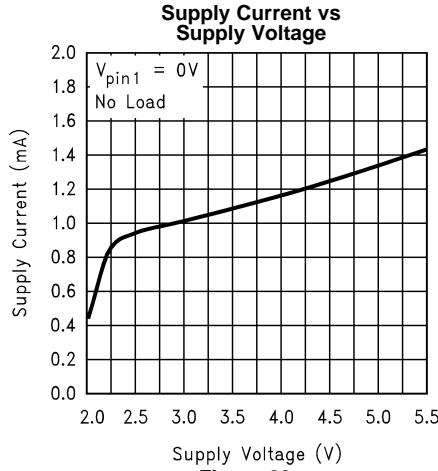


Figure 23.

APPLICATION INFORMATION

BRIDGE CONFIGURATION EXPLANATION

As shown in [Figure 1](#), the LM4818 consist of two operational amplifiers. External resistors, R_i and R_F set the closed-loop gain of the first amplifier (and the amplifier overall), whereas two internal $20\text{k}\Omega$ resistors set the second amplifier's gain at -1. The LM4818 is typically used to drive a speaker connected between the two amplifier outputs.

[Figure 1](#) shows that the output of Amp1 servers as the input to Amp2, which results in both amplifiers producing signals identical in magnitude but 180° out of phase. Taking advantage of this phase difference, a load is placed between V_{O1} and V_{O2} and driven differentially (commonly referred to as "bridge mode"). This results in a differential gain of

$$A_{VD} = 2 * (R_F/R_i) \quad (1)$$

Bridge mode is different from single-ended amplifiers that drive loads connected between a single amplifier's output and ground. For a given supply voltage, bridge mode has a distinct advantage over the single-ended configuration: its differential output doubles the voltage swing across the load. This results in four times the output power when compared to a single-ended amplifier under the same conditions. This increase in attainable output assumes that the amplifier is not current limited or the output signal is not clipped. To ensure minimum output signal clipping when choosing an amplifier's closed-loop gain, refer to the [AUDIO POWER AMPLIFIER DESIGN EXAMPLE](#) section.

Another advantage of the differential bridge output is no net DC voltage across the load. This results from biasing V_{O1} and V_{O2} at half-supply. This eliminates the coupling capacitor that single supply, single-ended amplifiers require. Eliminating an output coupling capacitor in a single-ended configuration forces a single supply amplifier's half-supply bias voltage across the load. The current flow created by the half-supply bias voltage increases internal IC power dissipation and may permanently damage loads such as speakers.

POWER DISSIPATION

Power dissipation is a major concern when designing a successful bridged or single-ended amplifier. [Equation 2](#) states the maximum power dissipation point for a single-ended amplifier operating at a given supply voltage and driving a specified load.

$$P_{DMAX} = (V_{DD})^2 / (2\pi^2 R_L) \text{ (W) Single-ended} \quad (2)$$

However, a direct consequence of the increased power delivered to the load by a bridged amplifier is an increase in the internal power dissipation point for a bridge amplifier operating at the same given conditions. [Equation 3](#) states the maximum power dissipation point for a bridged amplifier operating at a given supply voltage and driving a specified load.

$$P_{DMAX} = 4(V_{DD})^2 / (2\pi^2 R_L) \text{ (W) Bridge Mode} \quad (3)$$

The LM4818 has two operational amplifiers in one package and the maximum internal power dissipation is four times that of a single-ended amplifier. However, even with this substantial increase in power dissipation, the LM4818 does not require heatsinking. From [Equation 3](#), assuming a 5V power supply and an 8Ω load, the maximum power dissipation point is 633mW. The maximum power dissipation point obtained from [Equation 3](#) must not exceed the power dissipation predicted by [Equation 4](#):

$$P_{DMAX} = (T_{JMAX} - T_A) / \theta_{JA} \text{ (W)} \quad (4)$$

For the D package, $\theta_{JA} = 170^\circ\text{C/W}$ and $T_{JMAX} = 150^\circ\text{C}$ for the LM4818. For a given ambient temperature, T_A , [Equation 4](#) can be used to find the maximum internal power dissipation supported by the IC packaging. If the result of [Equation 3](#) is greater than the result of [Equation 4](#), then decrease the supply voltage, increase the load impedance, or reduce the ambient temperature. For a typical application using the D packaged LM4818 with a 5V power supply and an 8Ω load, the maximum ambient temperature that does not violate the maximum junction temperature is approximately 42°C . It is assumed that a device is a surface mount part operating around the maximum power dissipation point. The assumption that the device is operating around the maximum power dissipation point is incorrect for an 8Ω load. The maximum power dissipation point occurs when the output power is equal to the maximum power dissipation or 50% efficiency. The LM4818 is not capable of the output power level (633mW) required to operate at the maximum power dissipation point for an 8Ω load. To find the maximum

power dissipation, the graph [Figure 20](#) must be used. From the graph, the maximum power dissipation for an 8Ω load and a 5V supply is approximately 575mW. Substituting this value back into [Equation 4](#) for $P_{D\text{MAX}}$ and using $\theta_{JA} = 170^\circ\text{C}/\text{W}$ for the D package, the maximum ambient temperature is 52°C . Refer to the [TYPICAL PERFORMANCE CHARACTERISTICS](#) curves for power dissipation information for lower output powers and maximum power dissipation for each package at a given ambient temperature.

POWER SUPPLY BYPASSING

As with any power amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. The capacitors connected to the bypass and power supply pins should be placed as close to the LM4818 as possible. The capacitor connected between the bypass pin and ground improves the internal bias voltage's stability, producing improved PSRR. The improvements to PSRR increase as the bypass pin capacitor value increases. Typical applications employ a 5V regulator with $10\mu\text{F}$ and $0.1\mu\text{F}$ filter capacitors that aid in supply stability. Their presence, however, does not eliminate the need for bypassing the supply nodes of the LM4818. The selection of bypass capacitor values, especially C_B , depends on desired PSRR requirements, click and pop performance as explained in the section, [PROPER SELECTION OF EXTERNAL COMPONENTS](#), as well as system cost and size constraints.

SHUTDOWN FUNCTION

The voltage applied to the LM4818's SHUTDOWN pin controls the shutdown function. Activate micro-power shutdown by applying V_{DD} to the SHUTDOWN pin. When active, the LM4818's micro-power shutdown feature turns off the amplifier's bias circuitry, reducing the supply current. The logic threshold is typically $1/2V_{DD}$. The low $0.7\mu\text{A}$ typical shutdown current is achieved by applying a voltage that is as near as V_{DD} as possible to the SHUTDOWN pin. A voltage that is less than V_{DD} may increase the shutdown current. Avoid intermittent or unexpected micro-power shutdown by ensuring that the SHUTDOWN pin is not left floating but connected to either V_{DD} or GND.

There are a few ways to activate micro-power shutdown. These included using a single-pole, single-throw switch, a microcontroller, or a microprocessor. When using a switch, connect an external $10\text{k}\Omega$ to $100\text{k}\Omega$ pull-up resistor between the SHUTDOWN pin and V_{DD} . Connect the switch between the SHUTDOWN pin and ground. Select normal amplifier operation by closing the switch. Opening the switch connects the shutdown pin to V_{DD} through the pull-up resistor, activating micro-power shutdown. The switch and resistor ensure that the SHUTDOWN pin will not float. This prevents unwanted state changes. In a system with a microprocessor or a microcontroller, use a digital output to apply the control voltage to the SHUTDOWN pin. Driving the SHUTDOWN pin with active circuitry eliminates the pull-up resistor.

PROPER SELECTION OF EXTERNAL COMPONENTS

Optimizing the LM4818's performance requires properly selecting external components. Though the LM4818 operates well when using external components with wide tolerances, best performance is achieved by optimizing component values.

The LM4818 is unity gain stable, giving the designer maximum design flexibility. The gain should be set to no more than a given application requires. This allows the amplifier to achieve minimum THD+N and maximum signal-to-noise ratio. These parameters are compromised as the closed-loop gain increases. However, low gain demands input signals with greater voltage swings to achieve maximum output power. Fortunately, many signal sources such as audio CODECs have outputs of $1V_{\text{RMS}}$ ($2.83V_{\text{P-P}}$). Please refer to the [AUDIO POWER AMPLIFIER DESIGN EXAMPLE](#) section for more information on selecting the proper gain.

Another important consideration is the amplifier's close-loop bandwidth. To a large extent, the bandwidth is dictated by the choice of external components shown in [Figure 1](#). The input coupling capacitor, C_i , forms a first order high pass filter that limits low frequency response. This value should be chosen based on needed frequency response for a few distinct reasons discussed below.

Input Capacitor Value Selection

Amplifying the lowest audio frequencies requires a high value input coupling capacitor (C_i in [Figure 1](#)). A high value capacitor can be expensive and may compromise space efficiency in portable designs. In many cases the speakers used in portable systems, whether internal or external, have little ability to reproduce signals below 150Hz. Applications using speakers with limited frequency response reap little improvement by using a large input capacitor.

Besides affecting system cost and size, C_i has an effect on the LM4818's click and pop performance. When the supply voltage is first applied, a transient (pop) is created as the charge on the input capacitor changes from zero to a quiescent state. The magnitude of the pop is directly proportional to the input capacitor's value. Higher value capacitors need more time to reach a quiescent DC voltage (usually $1/2 V_{DD}$) when charged with a fixed current. The amplifier's output charges the input capacitor through the feedback resistor, R_F . Thus, selecting an input capacitor value that is no higher than necessary to meet the desired -3dB frequency can minimize pops.

As shown in [Figure 1](#), the input resistor (R_i) and the input capacitor, C_i produce a -3dB high pass filter cutoff frequency that is found using [Equation 5](#).

$$f_{-3dB} = 1/(2 \pi R_i C_i) \text{ (Hz)} \quad (5)$$

As an example when using a speaker with a low frequency limit of 150Hz, C_i , using [Equation 5](#) is $0.063\mu F$. The $0.39\mu F$ C_i shown in [Figure 1](#) allows the LM4818 to drive a high efficiency, full range speaker whose response extends down to 20Hz.

Besides optimizing the input capacitor value, the bypass capacitor value, C_B requires careful consideration. The bypass capacitor's value is the most critical to minimizing turn-on pops because it determines how fast the LM4818 turns on. The slower the LM4818's outputs ramp to their quiescent DC voltage (nominally $1/2 V_{DD}$), the smaller the turn-on pop. While the device will function properly (no oscillations or motorboating), with C_B less than $1.0\mu F$, the device will be much more susceptible to turn-on clicks and pops. Thus, a value of C_B equal to or greater than $1.0\mu F$ is recommended in all but the most cost sensitive designs.

Bypass Capacitor Value Selection

Besides minimizing the input capacitor size, careful consideration should be paid to the value of C_B , the capacitor connected to the BYPASS pin. Since C_B determines how fast the LM4818 settles to quiescent operation, its value is critical when minimizing turn-on pops. The slower the LM4818's outputs ramp to their quiescent DC voltage (nominally $1/2 V_{DD}$), the smaller the turn-on pop. Choosing C_B equal to $1.0\mu F$ along with a small value of C_i (in the range of $0.1\mu F$ to $0.39\mu F$) produces a click-less and pop-less shutdown function. As discussed above, choosing C_i no larger than necessary for the desired bandwidth helps minimize clicks and pops. If using the optional capacitor, C_{B2} , the total capacitance seen at the BYPASS pin is $C_B + C_{B2}$. When using the values shown in [Figure 1](#) for C_B and C_{B2} the change in the capacitance seen by the BYPASS pin is not significant relative to capacitor value tolerances.

Optimizing Click and Pop Reduction Performance

The LM4818 contains circuitry that minimizes turn-on and shutdown transients or "clicks and pops". For this discussion, turn on refers to either applying the power or supply voltage or when the shutdown mode is deactivated. While the power supply is ramping to its final value, the LM4818's internal amplifiers are configured as unity gain buffers. An internal current source charges the voltage of the bypass capacitor, C_B , connected to the BYPASS pin in a controlled, linear manner. Ideally, the input and outputs track the voltage charging on the bypass capacitor. The gain of the internal amplifiers remains unity until the bypass capacitor is fully charged to $1/2 V_{DD}$. As soon as the voltage on the bypass capacitor is stable, the device becomes fully operational. Although the BYPASS pin current cannot be modified, changing the size of the bypass capacitor, C_B , alters the device's turn-on time and magnitude of "clicks and pops". Increasing the value of C_B reduces the magnitude of turn-on pops. However, this presents a tradeoff: as the size of C_B increases, the turn-on time (T_{ON}) increases. There is a linear relationship between the size of C_B and the turn on time. If using the optional capacitor, C_{B2} , the total capacitance seen at the BYPASS pin is $C_B + C_{B2}$. The total capacitance seen at the BYPASS pin must be considered for the table below and when optimizing click and pop performance. Below are some typical turn-on times for various values of C_B :

| C_B | T_{ON} |
|-------------|----------|
| $0.01\mu F$ | 20ms |
| $0.1\mu F$ | 200ms |
| $0.22\mu F$ | 440ms |
| $0.47\mu F$ | 940ms |
| $1.0\mu F$ | 2S |

In order to eliminate "clicks and pops", all capacitors must be discharged before turn-on. Rapidly switching V_{DD} may not allow the capacitors to fully discharge, which may cause "clicks and pops".

AUDIO POWER AMPLIFIER DESIGN EXAMPLE

The following are the desired operational parameters:

Given:

| | |
|-----------------|----------------------|
| Power Output | 100mW |
| Load Impedance | 16Ω |
| Input Level | 1Vrms (max) |
| Input Impedance | 20kΩ |
| Bandwidth | 100Hz–20kHz ± 0.25dB |

The design begins by specifying the minimum supply voltage necessary to obtain the specified output power. To find this minimum supply voltage, use the [Output Power vs. Supply Voltage](#) graph in the [TYPICAL PERFORMANCE CHARACTERISTICS](#) section. From the graph for a 16Ω load, (graphs are for 8Ω, 16Ω, and 32Ω loads) the supply voltage for 100mW of output power with 1% THD+N is approximately 3.15 volts.

Additional supply voltage creates the benefit of increased headroom that allows the LM4818 to reproduce peaks in excess of 100mW without output signal clipping or audible distortion. The choice of supply voltage must also not create a situation that violates maximum dissipation as explained above in the [Power Dissipation](#) section. For example, if a 3.3V supply is chosen for extra headroom then according to [Equation 3](#) the maximum power dissipation point with a 16Ω load is 138mW. Using [Equation 4](#) the maximum ambient temperature is 126°C for the D package.

After satisfying the LM4818's power dissipation requirements, the minimum differential gain is found using [Equation 6](#).

$$A_{VD} \geq \sqrt{(P_0 R_L)} / (V_{IN}) = V_{orms} / V_{inrms} \quad (6)$$

Thus a minimum gain of 1.27 V/V allows the LM4818 to reach full output swing and maintain low noise and THD+N performance. For this example, let $A_{VD} = 1.27$. The amplifier's overall gain is set using the input (R_i) and feedback (R_F) resistors. With the desired input impedance set to 20kΩ, the feedback resistor is found using [Equation 7](#).

$$R_F / R_i = A_{VD} / 2 \quad (V/V) \quad (7)$$

The value of R_F is 13kΩ.

The last step in this design example is setting the amplifier's -3dB frequency bandwidth. To achieve the desired ±0.25dB pass band magnitude variation limit, the low frequency response must extend to at least one-fifth the lower bandwidth limit and the high frequency response must extend to at least five times the upper bandwidth limit. The gain variation for both response limits is 0.17dB, well within the ±0.25dB desired limit.

The results are:

$$f_L = 100Hz / 5 = 20Hz \quad (8)$$

$$f_H = 20 \text{ kHz} * 5 = 100\text{kHz} \quad (9)$$

As mentioned in the [PROPER SELECTION OF EXTERNAL COMPONENTS](#) section, R_i and C_i create a high pass filter that sets the amplifier's lower band pass frequency limit. Find the coupling capacitor's value using [Equation 10](#).

$$C_i \geq 1 / (2\pi R_i f_c) \quad (F) \quad (10)$$

$C_i \geq 0.398\mu\text{F}$, a standard value of $0.39\mu\text{F}$ will be used. The product of the desired high frequency cutoff (100kHz in this example) and the differential gain, A_{VD} , determines the upper pass band response limit. With $A_{VD} = 1.27$ and $f_H = 100\text{kHz}$, the closed-loop gain bandwidth product (GBWP) is 127kHz. This is less than the LM4818's 900kHz GBWP. With this margin the amplifier can be used in designs that require more differential gain while avoiding performance restricting bandwidth limitations.

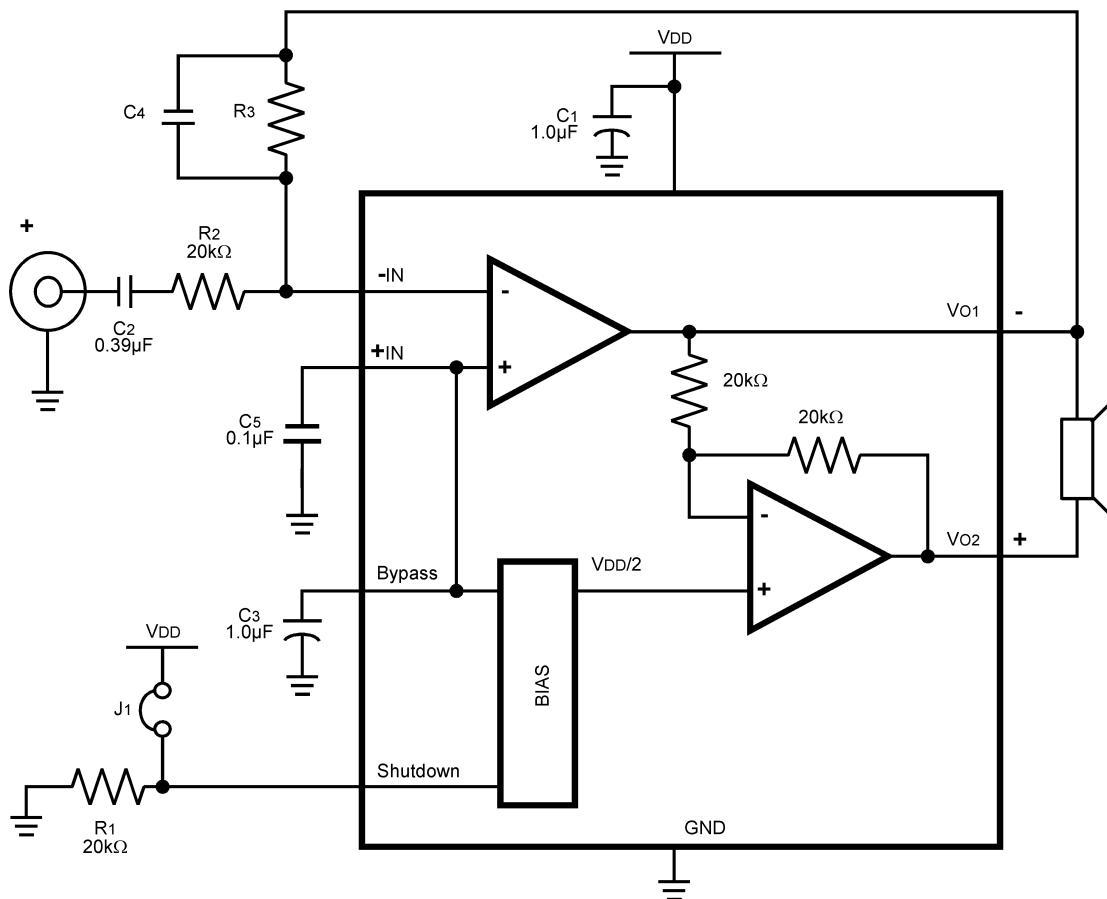


Figure 24. HIGHER GAIN AUDIO AMPLIFIER

The LM4818 is unity-gain stable and requires no external components besides gain-setting resistors, an input coupling capacitor, and proper supply bypassing in the typical application. However, if a closed-loop differential gain of greater than 10 is required, a feedback capacitor (C_4) may be needed as shown in [Figure 24](#) to bandwidth limit the amplifier. This feedback capacitor creates a low pass filter that eliminates possible high frequency oscillations. Care should be taken when calculating the -3dB frequency in that an incorrect combination of R_3 and C_4 will cause rolloff before 20kHz. A typical combination of feedback resistor and capacitor that will not produce audio band high frequency rolloff is $R_3 = 20\text{k}\Omega$ and $C_4 = 25\text{pF}$. These components result in a -3dB point of approximately 320 kHz. It is not recommended that the feedback resistor and capacitor be used to implement a band limiting filter below 100kHz.

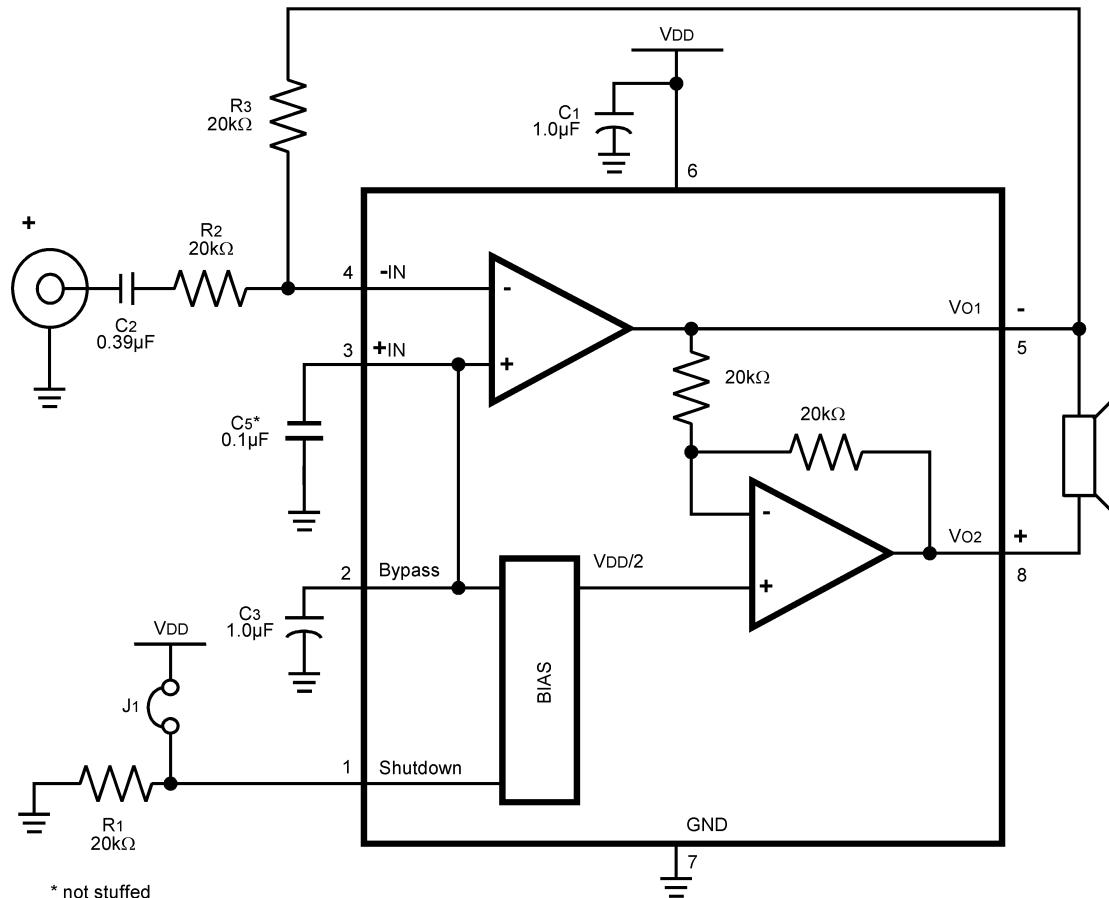
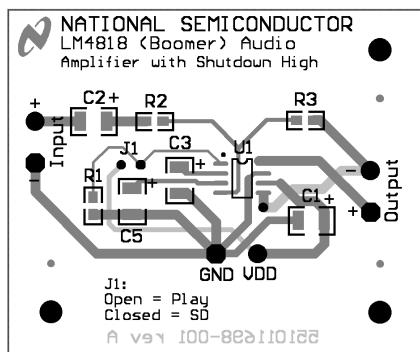


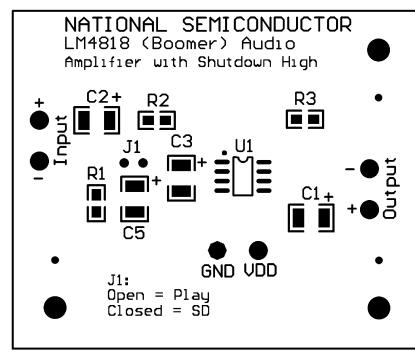
Figure 25. REFERENCE DESIGN BOARD and PCB LAYOUT GUIDELINES

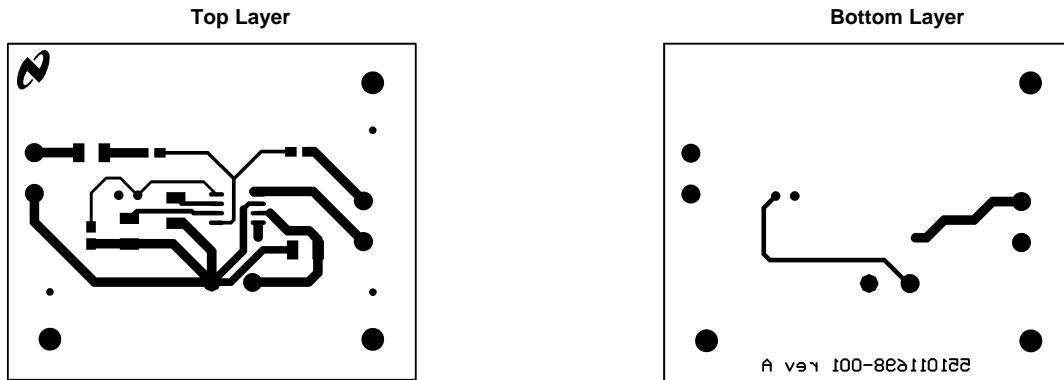
LM4818 SOIC DEMO BOARD ARTWORK

Composite View



Silk Screen





**Table 1. Mono LM4818 Reference Design Boards
Bill of Material for all Demo Boards**

| Item | Part Number | Part Description | Qty | Ref Designator |
|------|---------------|--|-----|----------------|
| 1 | 551011208-001 | LM4818 Mono Reference Design Board | 1 | |
| 10 | 482911183-001 | LM4818 Audio AMP | 1 | U1 |
| 20 | 151911207-001 | Tant Cap 1uF 16V 10 | 1 | C1 |
| 21 | 151911207-002 | Cer Cap 0.39uF 50V Z5U 20% 1210 | 1 | C2 |
| 25 | 152911207-001 | Tant Cap 1uF 16V 10 | 1 | C3 |
| 30 | 472911207-001 | Res 20K Ohm 1/10W 5 | 3 | R1, R2, R3 |
| 35 | 210007039-002 | Jumper Header Vertical Mount 2X1 0.100 | 2 | J1 |

PCB LAYOUT GUIDELINES

This section provides practical guidelines for mixed signal PCB layout that involves various digital/analog power and ground traces. Designers should note that these are only "rule-of-thumb" recommendations and the actual results will depend heavily on the final layout.

General Mixed Signal Layout Recommendation

Power and Ground Circuits

For two layer mixed signal design, it is important to isolate the digital power and ground trace paths from the analog power and ground trace paths. Star trace routing techniques (bringing individual traces back to a central point rather than daisy chaining traces together in a serial manner) can have a major impact on low level signal performance. Star trace routing refers to using individual traces to feed power and ground to each circuit or even device. This technique will take require a greater amount of design time but will not increase the final price of the board. The only extra parts required will be some jumpers.

Single-Point Power / Ground Connections

The analog power traces should be connected to the digital traces through a single point (link). A "Pi-filter" can be helpful in minimizing high frequency noise coupling between the analog and digital sections. It is further recommended to put digital and analog power traces over the corresponding digital and analog ground traces to minimize noise coupling.

Placement of Digital and Analog Components

All digital components and high-speed digital signals traces should be located as far away as possible from analog components and circuit traces.

Avoiding Typical Design / Layout Problems

Avoid ground loops or running digital and analog traces parallel to each other (side-by-side) on the same PCB layer. When traces must cross over each other do it at 90 degrees. Running digital and analog traces at 90 degrees to each other from the top to the bottom side as much as possible will minimize capacitive noise coupling and cross talk.

REVISION HISTORY

| Changes from Revision A (May 2013) to Revision B | Page |
|--|-------------|
| • Changed layout of National Data Sheet to TI format | 16 |

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead/Ball Finish | MSL Peak Temp (3) | Op Temp (°C) | Top-Side Markings (4) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-------------------------|------------------|----------------------|--------------|--------------------------|----------------|
| LM4818MX/NOPB | ACTIVE | SOIC | D | 8 | 2500 | Green (RoHS & no Sb/Br) | CU SN | Level-1-260C-UNLIM | -40 to 85 | LM48 18M | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

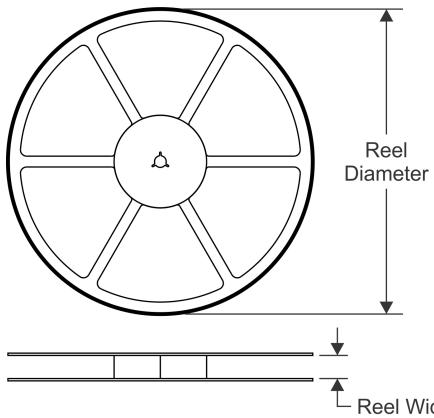
(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "—" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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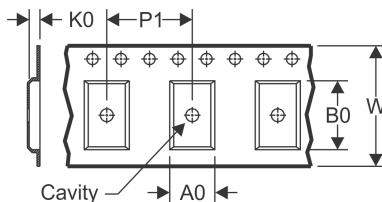
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TAPE AND REEL INFORMATION

REEL DIMENSIONS

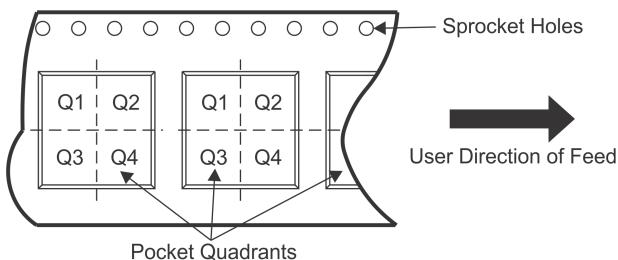


TAPE DIMENSIONS



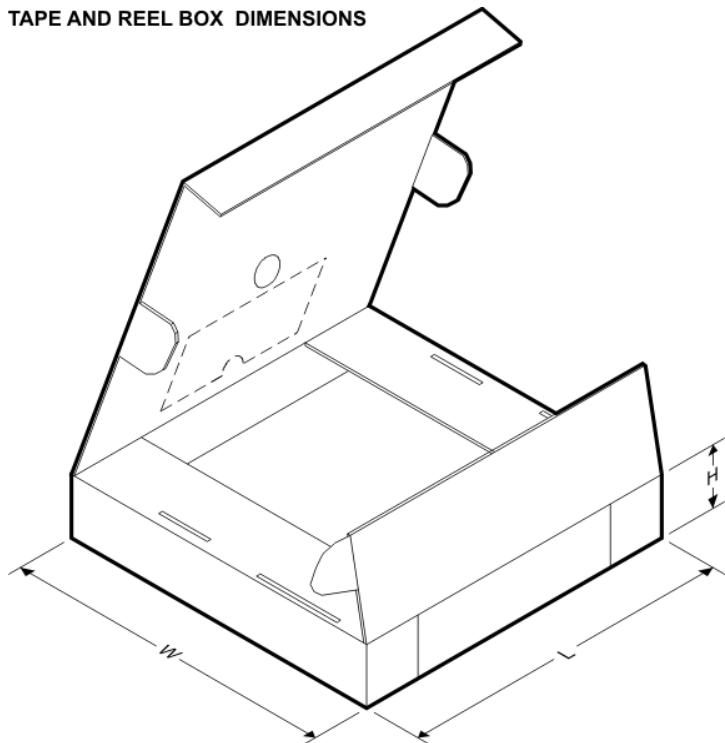
| | |
|----|---|
| A0 | Dimension designed to accommodate the component width |
| B0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| LM4818MX/NOPB | SOIC | D | 8 | 2500 | 330.0 | 12.4 | 6.5 | 5.4 | 2.0 | 8.0 | 12.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS

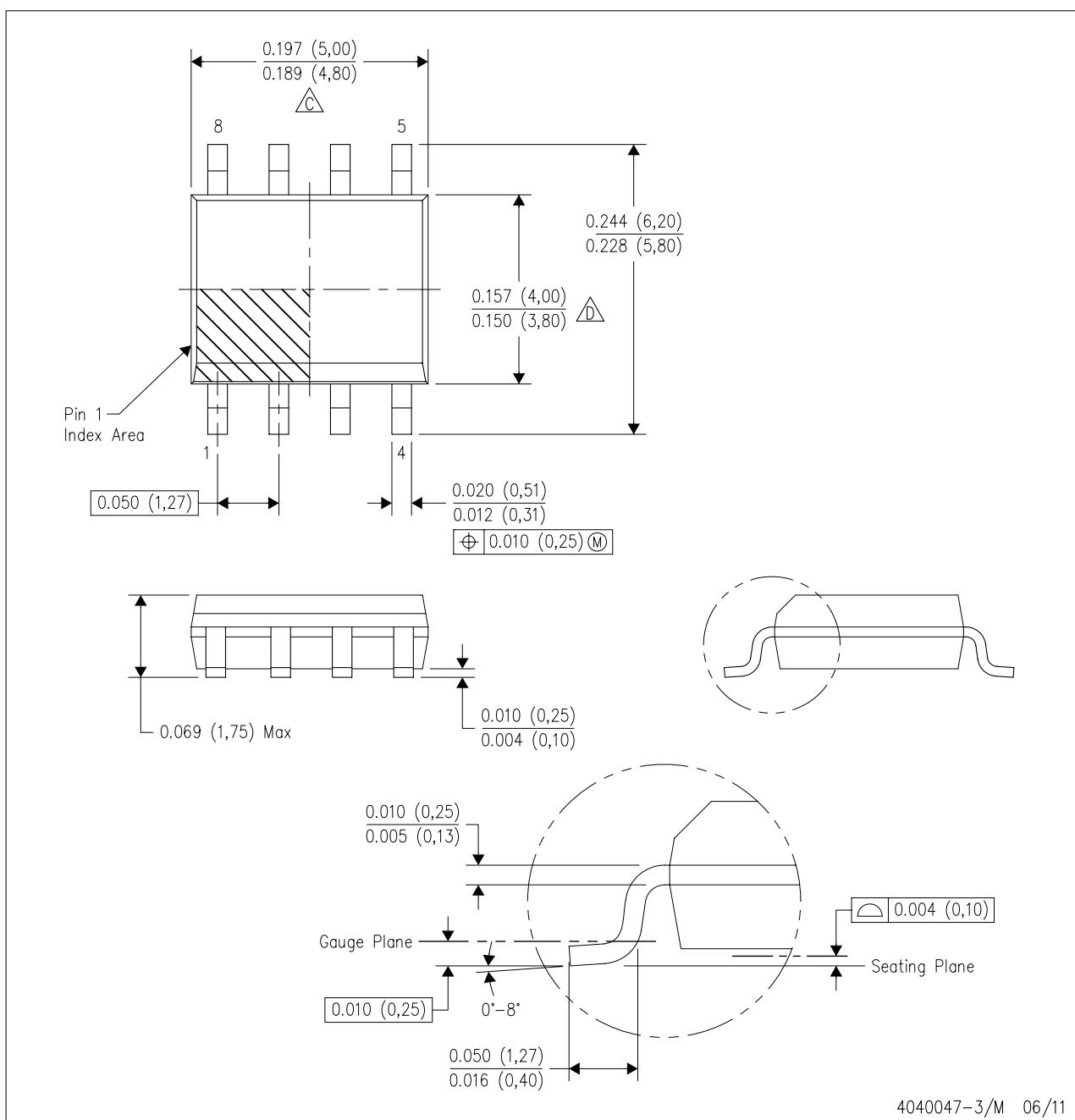
*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM4818MX/NOPB | SOIC | D | 8 | 2500 | 367.0 | 367.0 | 35.0 |

MECHANICAL DATA

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.

 Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.

 Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 Reference JEDEC MS-012 variation AA

E. Reference JEDEC MS-012 variation AA.

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